terminal, said resistors being connected in parallel with each other, and having no resistor connected between said transistors and ground, to discharge static electricity through said transistors to ground and avoid reduction in gain.

- 2. (Amended) An ESD protection circuit comprising:
- a substrate;
- a transistor formed on the substrate:
- a first insulating film formed on the substrate inclusive of the transistor and having a first contact hole to an input terminal of transistor;
- a buffered layer formed on the first insulating film inclusive of the first contact hole and electrically connected to the input terminal for acting as a resistor;
- a second insulating film formed on the first insulating film inclusive of the buffered layer and having a second contact hole to the buffered layer; and,
- a pad formed on the second insulating film inclusive of the second contact hole and electrically connected to the buffered layer, for discharging static electricity from said pad, through the buffered layer, and through said transistor to ground.
- 3. (Twice Amended) A method for fabricating an ESD protection circuit, comprising the steps of:

Application No.: 09/452,809

Art Unit 2814

Attorney Docket No. 0465-0636P Amendment filed on October 17, 2002

Page 3

(1) forming a transistor on a substrate;

(2) forming a first insulating film on the substrate inclusive of the

transistor and having a first contact hole to an input terminal of the transistor;

(3) forming a buffered layer in the first contact hole and the first

insulating film in the vicinity of the first contact hole;

(4) forming a second insulating film on the first insulating film inclusive

of the buffered layer and having a second contact hole to the buffered layer;

and,

(5) forming a pad both on the second contact hole and the second

insulating film in the vicinity of the second contact hole, for discharging static

electricity from said pad, through the buffered layer, and through said

transistor to ground.

6. (Amended) An ESC (Electro-Static-Discharge) protection circuit

comprising:

a pad and a main chip; and

a plurality of transistors, each connected between the pad and the main

chip, having resistors connected to an input terminal only, to discharge static

electricity through said transistors to ground and avoid reduction in gain.